



MJ2955;STM;TO3;tranzystor; PNP;15A;60V;115W;2.5MHz;Pbf



Dane techniczne:

Nazwa: MJ2955

Typ tranzystora: bipolarny

Kierunek przewodnictwa: PNP

Prąd kolektora: 15A

Napięcie kolektor-emiter: 60V

Moc: 115W

Częstotliwość: 2.5 MHz

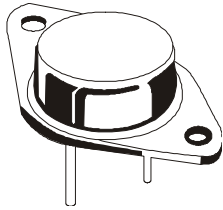
Montaż: przewlekany(THT)

Obudowa: TO3

Producent: STM

SILICON PLANAR POWER TRANSISTORS

2N3055 NPN
MJ2955 PNP



TO-3
Metal Can Package

General Purpose Switching and Amplifier Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Base Voltage	V_{CBO}	100	V
Collector Emitter Voltage	V_{CEO}	60	V
Collector Emitter Voltage ($R_{BE}=100\Omega$)	V_{CER}	70	V
Emitter Base Voltage	V_{EBO}	7	V
Collector Current Continuous	I_C	15	A
Base Current	I_B	7	A
Power Dissipation @ $T_c=25^\circ\text{C}$	P_{tot}	115	W
Derate Above 25°C		0.657	W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_j, T_{stg}	- 65 to +200	$^\circ\text{C}$

THERMAL RESISTANCE

Junction to Case	$R_{th(j-c)}$	1.52	$^\circ\text{C/W}$
------------------	---------------	------	--------------------

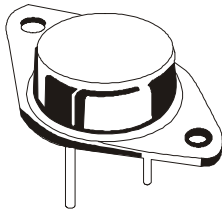
ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Sustaining Voltage	$V_{CEO(sus)}$ *	$I_C=200\text{mA}, I_B=0$	60		V
Collector Emitter Sustaining Voltage	$V_{CER(sus)}$ *	$I_C=200\text{mA}, R_{BE}=100\Omega$	70		V
Collector Cut off Current	I_{CEX}	$V_{CE}=100\text{V}, V_{BE}(\text{off})=1.5\text{V}$ $T_c=150^\circ\text{C}$ $V_{CE}=100\text{V}, V_{BE}(\text{off})=1.5\text{V}$		1.0 5.0	mA
Collector Cut off Current	I_{CEO}	$V_{CE}=30\text{V}, I_B=0$		0.7	mA
Emitter Cut off Current	I_{EBO}	$V_{BE}=7\text{V}, I_C=0$		5.0	mA
Collector Emitter Saturation Voltage	$V_{CE(\text{Sat})}$ *	$I_C=4\text{A}, I_B=400\text{mA}$ $I_C=10\text{A}, I_B=3.3\text{A}$		1.1 3.0	V
Base Emitter on Voltage	$V_{BE(\text{on})}$ *	$I_C=4\text{A}, V_{CE}=4\text{V}$		1.5	V
DC Current Gain	h_{FE} *	$I_C=4\text{A}, V_{CE}=4\text{V}$ $I_C=10\text{A}, V_{CE}=4\text{V}$	20 5	70	

SILICON PLANAR POWER TRANSISTOR

2N3055 NPN
MJ2955 PNP

TO-3
Metal Can Package



ELECTRICAL CHARACTERISTICS (T_c=25°C unless specified otherwise)

Second Breakdown

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Second Breakdown Collector Current with Base Forward Biased	$I_{S/b}$	$V_{CE}=40V, t=1.0 \text{ s, Nonrepetitive}$	2.87		A

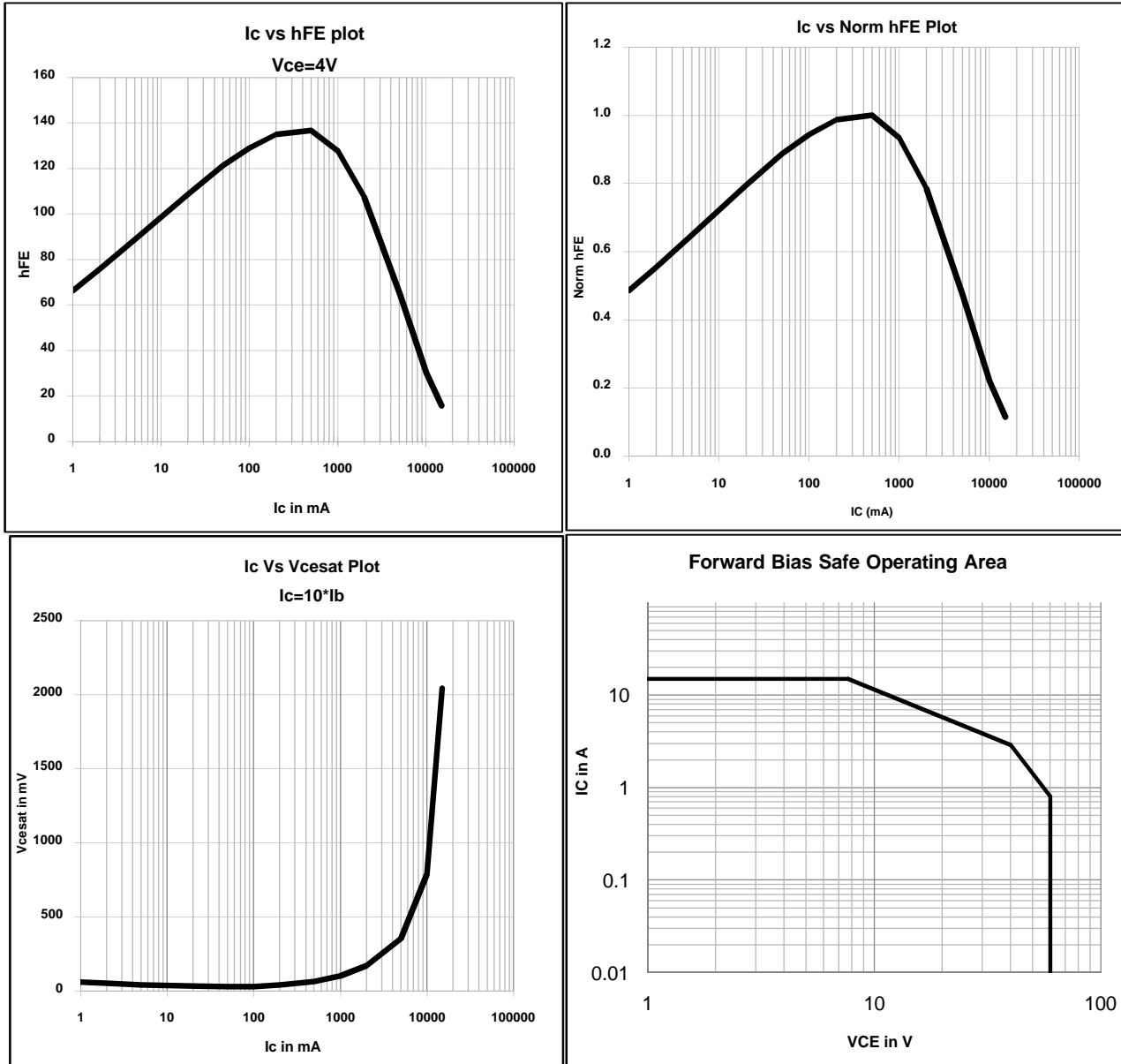
Dynamic Characteristics

Current Gain - Bandwidth Product	f_T	$I_C=0.5A, V_{CE}=10V, f=1MHz$	2.5		MHz
Small Signal Current Gain	h_{fe}	$I_C=1A, V_{CE}=4V, f=1KHz$	15	120	
Small Signal Current Gain Cutoff Frequency	$f_{h_{fe}}$	$I_C=1A, V_{CE}=4V, f=1KHz$	10		KHz

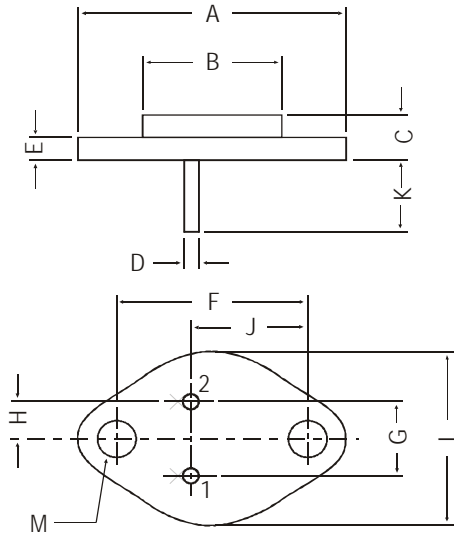
*Pulse Test: Pulse Width $\leq 300ms$, Duty Cycle $\leq 2\%$



CHARACTERISTICS PLOTS

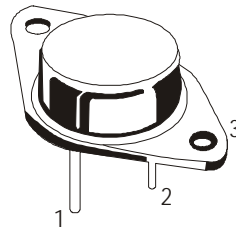


TO-3 Metal Can Package



All dimensions in mm.

DIM	MIN.	MAX.
A	—	39.37
B	—	22.22
C	6.35	8.50
D	0.96	1.09
E	—	1.77
F	29.90	30.40
G	10.69	11.18
H	5.20	5.72
J	16.64	17.15
K	11.15	12.25
L	—	26.67
M	3.84	4.19



PIN CONFIGURATION

1. BASE
2. EMITTER
3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-3	100 pcs/pkt	1.3 kg/100 pcs	12.5" x 8" x 1.8"	0.1K	17" x 11.5" x 21"	2K	27.5 kgs



Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of

Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290

e-mail sales@cdil.com www.cdil.com